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### Understanding **Embedded - FPGAs (Field Programmable Gate Array)**

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

#### **Details**

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	300000
Total RAM Bits	21094400
Number of I/O	300
Number of Gates	-
Voltage - Supply	0.97V ~ 1.08V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	536-LFBGA, CSPBGA
Supplier Device Package	536-CSPBGA (16x16)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/microchip-technology/mpf300ts-1fcsg536i">https://www.e-xfl.com/product-detail/microchip-technology/mpf300ts-1fcsg536i</a>

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## 2 Overview

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This datasheet describes PolarFire® FPGA device characteristics with industrial temperature range ( $-40^{\circ}\text{C}$  to  $100^{\circ}\text{C}$   $T_{\text{j}}$ ) and extended commercial temperature range ( $0^{\circ}\text{C}$  to  $100^{\circ}\text{C}$   $T_{\text{j}}$ ). The devices are provided with a standard speed grade (STD) and a  $-1$  speed grade with higher performance. The FPGA core supply  $V_{\text{DD}}$  can operate at 1.0 V for lower-power or 1.05 V for higher performance. Similarly, the transceiver core supply  $V_{\text{DDA}}$  can also operate at 1.0 V or 1.05 V. Users select the core operating voltage while creating the Libero project.

## 4 Device Offering

The following table lists the PolarFire FPGA device options using the MPF300T as an example. The MPF100T, MPF200T, and MPF500T device densities have identical offerings.

**Table 1 • PolarFire FPGA Device Options**

Device Options	Extended Commercial 0 °C–100 °C	Industrial –40 °C–100 °C	STD	–1	Transceivers	Lower Static Power L	Data Security S
MPF300T	Yes	Yes	Yes	Yes	Yes		
MPF300TL	Yes	Yes	Yes		Yes	Yes	
MPF300TS		Yes	Yes	Yes	Yes		Yes
MPF300TLS		Yes	Yes		Yes	Yes	Yes

I/O Standard	Bank Type	V <sub>O<sub>CM</sub></sub> <sup>1</sup> Min (V)	V <sub>O<sub>CM</sub></sub> Typ (V)	V <sub>O<sub>CM</sub></sub> Max (V)	V <sub>O<sub>D</sub></sub> <sup>2</sup> Min (V)	V <sub>O<sub>D</sub></sub> <sup>2</sup> Typ (V)	V <sub>O<sub>D</sub></sub> <sup>2</sup> Max (V)
MILVDS25 <sup>3</sup>	GPIO		1.25		0.396	0.442	0.453
LVPECLE33 <sup>3</sup>	GPIO		1.65		0.664	0.722	0.755
MIPIE25 <sup>3</sup>	GPIO		0.25		0.1	0.22	0.3

1. V<sub>O<sub>CM</sub></sub> is the output common mode voltage.
2. V<sub>O<sub>D</sub></sub> is the output differential voltage.
3. Emulated output only.

### 6.3.3 Complementary Differential DC Input and Output Levels

The following tables list the complementary differential DC I/O levels.

**Table 16 • Complementary Differential DC Input Levels**

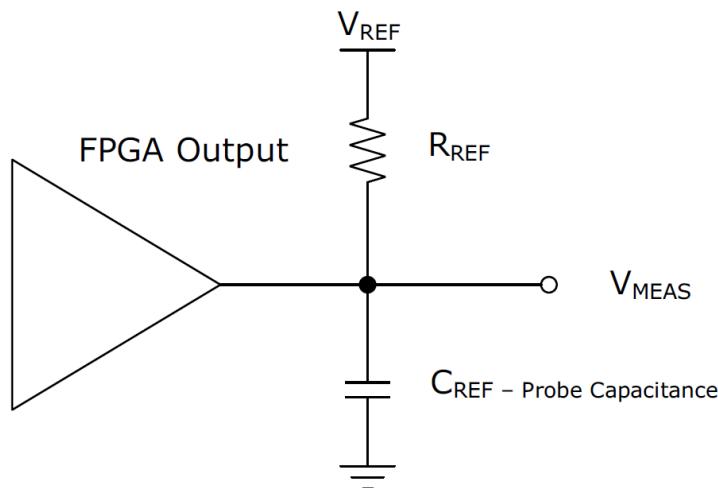
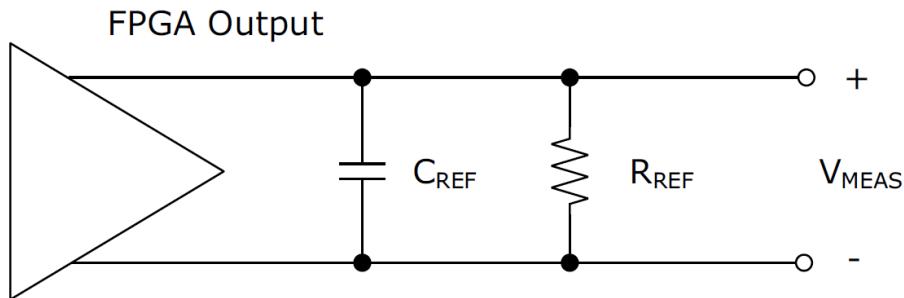
I/O Standard	V <sub>DDI</sub> Min (V)	V <sub>DDI</sub> Typ (V)	V <sub>DDI</sub> Max (V)	V <sub>I<sub>CM</sub></sub> <sup>1,3</sup> Min (V)	V <sub>I<sub>CM</sub></sub> <sup>1,3</sup> Typ (V)	V <sub>I<sub>CM</sub></sub> <sup>1,3</sup> Max (V)	V <sub>I<sub>D</sub></sub> <sup>2</sup> Min (V)	V <sub>I<sub>D</sub></sub> Max (V)
SSTL25I	2.375	2.5	2.625	1.164	1.250	1.339	0.1	
SSTL25II	2.375	2.5	2.625	1.164	1.250	1.339	0.1	
SSTL18I	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
SSTL18II	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
SSTL15I	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
SSTL15II	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
SSTL135I	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
SSTL135II	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL15I	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
HSTL15II	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
HSTL135I	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL135II	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL12I	1.14	1.2	1.26	0.559	0.600	0.643	0.1	
HSUL18I	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
HSUL18II	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
HSUL12I	1.14	1.2	1.26	0.559	0.600	0.643	0.1	
POD12I	1.14	1.2	1.26	0.787	0.840	0.895	0.1	
POD12II	1.14	1.2	1.26	0.787	0.840	0.895	0.1	

1. V<sub>I<sub>CM</sub></sub> is the input common mode voltage.
2. V<sub>I<sub>D</sub></sub> is the input differential voltage.
3. V<sub>I<sub>CM</sub></sub> rules are as follows:
  - a. V<sub>I<sub>CM</sub></sub> must be less than V<sub>DDI</sub> - 0.4V;
  - b. V<sub>I<sub>CM</sub></sub> + V<sub>I<sub>D</sub></sub>/2 must be < V<sub>DDI</sub> + 0.4 V;
  - c. V<sub>I<sub>CM</sub></sub> - V<sub>I<sub>D</sub></sub>/2 must be > V<sub>SS</sub> - 0.3 V.

Parameter	Description	Min (%)	Typ	Max (%)	Unit	Condition
Single-ended termination to V <sub>ss</sub> <sup>4,5</sup>	Internal parallel termination to V <sub>ss</sub>	-20	120	20	Ω	V <sub>DDI</sub> = 2.5 V/1.8 V/1.5 V/1.2 V
		-20	240	20	Ω	V <sub>DDI</sub> = 2.5 V/1.8 V/1.5 V/1.2 V

1. Measured across P to N with 400 mV bias.
2. Thevenin impedance is calculated based on independent P and N as measured at 50% of V<sub>DDI</sub>.
3. For 50 Ω/75 Ω/150 Ω cases, nearest supported values of 40 Ω/60 Ω/120 Ω are used.
4. Measured at 50% of V<sub>DDI</sub>.
5. Supported terminations vary with the IO type regardless of V<sub>DDI</sub> nominal voltage. Refer to Libero for available combinations.

Standard	Description	V <sub>L</sub> <sup>1</sup>	V <sub>H</sub> <sup>1</sup>	V <sub>ID</sub> <sup>2</sup>	V <sub>ICM</sub> <sup>2</sup>	V <sub>MEAS</sub> <sup>3,4</sup>	V <sub>REF</sub> <sup>1,5</sup>	Unit
SLVS25	SLVS 2.5 V	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.200	0		V
SLVS18	SLVS 1.8 V	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.200	0		V
HCSL33	High-speed current steering logic (HCSL) 3.3 V	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.350	0		V
HCSL25	HCSL 2.5 V	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.350	0		V
HCSL18	HCSL 1.8 V	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.350	0		V
BLVDSE25 <sup>6</sup>	Bus LVDS 2.5 V	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	1.250	0		V
MLVDSE25 <sup>6</sup>	Multipoint LVDS 2.5 V	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	1.250	0		V
LVPECL33	Low-voltage positive emitter coupled logic	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	1.650	0		V
LVPECLE33 <sup>6</sup>	Low-voltage positive emitter coupled logic	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	1.650	0		V
SSTL25I	Differential SSTL 2.5 V Class I	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	1.250	0		V
SSTL25II	Differential SSTL 2.5 V Class II	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	1.250	0		V
SSTL18I	Differential SSTL 1.8 V Class I	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.900	0		V
SSTL18II	Differential SSTL 1.8 V Class II	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.900	0		V
SSTL15	Differential SSTL 1.5 V Class I	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.750	0		V
SSTL135	Differential SSTL 1.5 V Class II	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.750	0		V
HSTL15I	Differential HSTL 1.5 V Class I	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.750	0		V
HSTL15II	Differential HSTL 1.5 V Class II	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.750	0		V
HSTL135I	Differential HSTL 1.35 V Class I	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.675	0		V

**Figure 1 • Output Delay Measurement—Single-Ended Test Setup****Figure 2 • Output Delay Measurement—Differential Test Setup**

### 7.1.3 Input Buffer Speed

The following tables provide information about input buffer speed.

**Table 24 • HSIO Maximum Input Buffer Speed**

Standard	STD	-1	Unit
LVDS18	1250	1250	Mbps
RSDS18	800	800	Mbps
MINILVDS18	800	800	Mbps
SUBLVDS18	800	800	Mbps
PPDS18	800	800	Mbps
SLVS18	800	800	Mbps
SSTL18I	800	1066	Mbps
SSTL18II	800	1066	Mbps
SSTL15I	1066	1333	Mbps
SSTL15II	1066	1333	Mbps
SSTL135I	1066	1333	Mbps
SSTL135II	1066	1333	Mbps

Standard	STD	-1	Unit
HSTL15I	900	1100	Mbps
HSTL15II	900	1100	Mbps
HSTL135I	1066	1066	Mbps
HSTL135II	1066	1066	Mbps
HSUL18I	400	400	Mbps
HSUL18II	400	400	Mbps
HSUL12	1066	1333	Mbps
HSTL12	1066	1266	Mbps
POD12I	1333	1600	Mbps
POD12II	1333	1600	Mbps
LVCMOS18 (12 mA)	500	500	Mbps
LVCMOS15 (10 mA)	500	500	Mbps
LVCMOS12 (8 mA)	300	300	Mbps

1. Performance is achieved with  $V_{ID} \geq 200$  mV.

**Table 25 • GPIO Maximum Input Buffer Speed**

Standard	STD	-1	Unit
LVDS25/LVDS33/LCMDS25/LCMDS33	1250	1600	Mbps
RSDS25/RSDS33	800	800	Mbps
MINILVDS25/MINILVDS33	800	800	Mbps
SUBLVDS25/SUBLVDS33	800	800	Mbps
PPDS25/PPDS33	800	800	Mbps
SLVS25/SLVS33	800	800	Mbps
SLVSE15	800	800	Mbps
HCSL25/HCSL33	800	800	Mbps
BUSLVDS25	800	800	Mbps
MLVDSE25	800	800	Mbps
LVPECL33	800	800	Mbps
SSTL25I	800	800	Mbps
SSTL25II	800	800	Mbps
SSTL18I	800	800	Mbps
SSTL18II	800	800	Mbps
SSTL15I	800	1066	Mbps
SSTL15II	800	1066	Mbps
HSTL15I	800	900	Mbps
HSTL15II	800	900	Mbps
HSUL18I	400	400	Mbps
HSUL18II	400	400	Mbps
PCI	500	500	Mbps
LTTL33 (20 mA)	500	500	Mbps
LVCMOS33 (20 mA)	500	500	Mbps
LVCMOS25 (16 mA)	500	500	Mbps

Parameter	Interface Name	Topology	STD Min	STD Typ	STD Max	-1 Min	-1 Typ	-1 Max	Unit	Clock-to- Data Condition
$F_{MAX}$ 4:1	RX_DDRX_B_A	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, aligned
$F_{MAX}$ 8:1	RX_DDRX_B_A	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, aligned
$F_{MAX}$ 2:1	RX_DDRX_B_C	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered
$F_{MAX}$ 4:1	RX_DDRX_B_C	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered
$F_{MAX}$ 8:1	RX_DDRX_B_C	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered
$F_{MAX}$ 2:1	RX_DDRX_BL_A	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, aligned
$F_{MAX}$ 4:1	RX_DDRX_BL_A	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, aligned
$F_{MAX}$ 8:1	RX_DDRX_BL_A	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, aligned
$F_{MAX}$ 2:1	RX_DDRX_BL_C	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered
$F_{MAX}$ 4:1	RX_DDRX_BL_C	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered

### 7.3.2 SRAM Blocks

The following tables describe the LSRAM blocks' performance.

**Table 43 • LSRAM Performance Industrial Temperature Range (−40 °C to 100 °C)**

Parameter	V <sub>DD</sub> = 1.0 V – STD	V <sub>DD</sub> = 1.0 V – 1	V <sub>DD</sub> = 1.05 V – STD	V <sub>DD</sub> = 1.05 V – 1	Unit	Condition
Operating frequency	343	428	343	428	MHz	Two-port, all supported widths, pipelined, simple-write, and write-feed-through
	309	428	309	428	MHz	Two-port, all supported widths, non-pipelined, simple-write, and write-feed-through
	343	428	343	428	MHz	Dual-port, all supported widths, pipelined, simple-write, and write-feed-through
	309	428	309	428	MHz	Dual-port, all supported widths, non-pipelined, simple-write, and write-feed-through
	343	428	343	428	MHz	Two-port pipelined ECC mode, pipelined, simple-write, and write-feed-through
	279	295	279	295	MHz	Two-port non-pipelined ECC mode, pipelined, simple-write, and write-feed-through
	343	428	343	428	MHz	Two-port pipelined ECC mode, non-pipelined, simple-write, and write-feed-through
	196	285	196	285	MHz	Two-port non-pipelined ECC mode, non-pipelined, simple-write, and write-feed-through
	274	285	274	285	MHz	Two-port, all supported widths, pipelined, and read-before-write
	274	285	274	285	MHz	Two-port, all supported widths, non-pipelined, and read-before-write
	274	285	274	285	MHz	Dual-port, all supported widths, pipelined, and read-before-write
	274	285	274	285	MHz	Dual-port, all supported widths, non-pipelined, and read-before-write
	274	285	274	285	MHz	Two-port pipelined ECC mode, pipelined, and read-before-write
	274	285	274	285	MHz	Two-port non-pipelined ECC mode, pipelined, and read-before-write
	274	285	274	285	MHz	Two-port pipelined ECC mode, non-pipelined, and read-before-write
	193	285	193	285	MHz	Two-port non-pipelined ECC mode, non-pipelined, and read-before-write

### 7.6.3 FPGA Bitstream Sizes

The following table describes FPGA bitstream sizes.

**Table 72 • Initialization Client Sizes**

Device	Plaintext	Ciphertext
MPF100T, TL, TS, TLS		
MPF200T, TL, TS, TLS	2916 KB	3006 KB
MPF300T, TL, TS, TLS	4265 KB	4403 KB
MPF500T, TL, TS, TLS		

**Note:** Worst case initializing all fabric LSRAM, USRAM, and UPROM.

**Table 73 • Bitstream Sizes**

File	Devices	FPGA	Security	SNVM (all pages)	FPGA+ SNVM	FPGA+ Sec	SNVM+ Sec	FPGA+ SNVM+ Sec
SPI	MPF100T, TL, TS, TLS							
DAT	MPF100T, TL, TS, TLS							
SPI	MPF200T, TL, TS, TLS	5.9 MB	3.4 KB	59.7 KB	5.9 MB	5.9 MB	62.2 KB	6.0 MB
DAT	MPF200T, TL, TS, TLS	5.9 MB	7.3 KB	61.2 KB	6.0 MB	5.9 MB	66.3 KB	6.0 MB
SPI	MPF300T, TL, TS, TLS	9.3 MB	3.5 KB	59.7 KB	9.6 MB	9.5 MB	62.2 KB	9.6 MB
DAT	MPF300T, TL, TS, TLS	9.3 MB	7.6 KB	61.2 KB	9.6 MB	9.5 MB	66.3 KB	9.6 MB
SPI	MPF500T, TL, TS, TLS							
DAT	MPF500T, TL, TS, TLS							

### 7.6.4 Digest Cycles

Digests verify the integrity of the programmed non-volatile data. Digests are a cryptographic hash of various data areas. Any digest that reports back an error raises the digest tamper flag.

**Table 74 • Maximum Number of Digest Cycles**

Retention Since Programmed (N = Number Digests During that Time) <sup>1</sup>										
Digest $T_J$	Storage and Operating $T_J$	N $\leq 300$	N = 500	N = 1000	N = 1500	N = 2000	N = 4000	N = 6000	Unit	Retention
-40 to 100	-40 to 100	20 × LF	17 × LF	12 × LF	10 × LF	8 × LF	4 × LF	2 × LF	°C	Years
-40 to 100	0 to 100	20 × LF	17 × LF	12 × LF	10 × LF	8 × LF	4 × LF	2 × LF	°C	Years
-40 to 85	-40 to 85	20 × LF	20 × LF	20 × LF	20 × LF	16 × LF	8 × LF	4 × LF	°C	Years
-40 to 55	-40 to 55	20 × LF	20 × LF	20 × LF	20 × LF	20 × LF	20 × LF	20 × LF	°C	Years

1. LF = Lifetime factor as defined by the number of programming cycles the device has seen under the conditions listed in the following table.

Parameter	Typ	Max	Unit	Conditions
Time to destroy data in non-volatile memory (recoverable) <sup>1,3</sup>			ms	One iteration of scrubbing
Time to destroy data in non-volatile memory (non-recoverable) <sup>1,4</sup>			ms	One iteration of scrubbing
Time to scrub the fabric data <sup>1</sup>			s	Full scrubbing
Time to scrub the pNVM data (like new) <sup>1,2</sup>			s	Full scrubbing
Time to scrub the pNVM data (recoverable) <sup>1,3</sup>			s	Full scrubbing
Time to scrub the fabric data pNVM data (non-recoverable) <sup>1,4</sup>			s	Full scrubbing
Time to verify <sup>5</sup>			s	

1. Total completion time after interning zeroization.
2. Like new mode—zeroizes user design security setting and sNVM content.
3. Recoverable mode—zeroizes user design security setting, sNVM and factory keys.
4. Non-recoverable mode—zeroizes user design security setting, sNVM and factory keys, and factory data required for programming.
5. Time to verify after scrubbing completes.

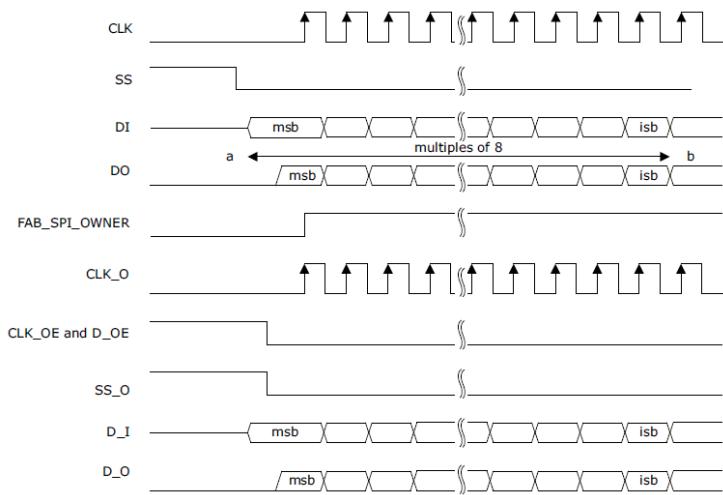
**Table 79 • Zeroization Times for MPF300T, TL, TS, and TLS Devices**

Parameter	Typ	Max	Unit	Conditions
Time to enter zeroization			ms	Zip flag set
Time to destroy the fabric data <sup>1</sup>			ms	Data erased
Time to destroy data in non-volatile memory (like new) <sup>1,2</sup>			ms	One iteration of scrubbing
Time to destroy data in non-volatile memory (recoverable) <sup>1,3</sup>			ms	One iteration of scrubbing
Time to destroy data in non-volatile memory (non-recoverable) <sup>1,4</sup>			ms	One iteration of scrubbing
Time to scrub the fabric data <sup>1</sup>			s	Full scrubbing
Time to scrub the pNVM data (like new) <sup>1,2</sup>			s	Full scrubbing
Time to scrub the pNVM data (recoverable) <sup>1,3</sup>			s	Full scrubbing
Time to scrub the fabric data pNVM data (non-recoverable) <sup>1,4</sup>			s	Full scrubbing
Time to verify <sup>5</sup>			s	

1. Total completion time after interning zeroization.
2. Like new mode—zeroizes user design security setting and sNVM content.
3. Recoverable mode—zeroizes user design security setting, sNVM and factory keys.
4. Non-recoverable mode—zeroizes user design security setting, sNVM and factory keys, and factory data required for programming.
5. Time to verify after scrubbing completes.

**Table 80 • Zeroization Times for MPF500T, TL, TS, and TLS Devices**

Parameter	Typ	Max	Unit	Conditions
Time to enter zeroization			ms	Zip flag set
Time to destroy the fabric data <sup>1</sup>			ms	Data erased
Time to destroy data in non-volatile memory (like new) <sup>1,2</sup>			ms	One iteration of scrubbing
Time to destroy data in non-volatile memory (recoverable) <sup>1,3</sup>			ms	One iteration of scrubbing

**Figure 4 • USPI Switching Characteristics**

## 7.8.4 Tamper Detectors

The following section describes tamper detectors.

**Table 91 • ADC Conversion Rate**

Parameter	Description	Min	Typ <sup>1</sup>	Max
T <sub>CONV1</sub>	Time from enable changing from zero to non-zero value to first conversion completes. Minimum value applies when POWEROFF = 0.	420 $\mu$ s		470 $\mu$ s
T <sub>CONVN</sub>	Time between subsequent channel conversions.		480 $\mu$ s	
T <sub>SETUP</sub>	Data channel and output to valid asserted. Data is held until next conversion completes, that is >480 $\mu$ s.	0 ns		
T <sub>VALID<sup>2</sup></sub>	Width of the valid pulse.	1.625 $\mu$ s		2 $\mu$ s
T <sub>RATE</sub>	Time from start of first set of conversions to the start of the next set. Can be considered as the conversion rate. Is set by the conversion rate parameter.	480 $\mu$ s	Rate $\times$ 32 $\mu$ s	8128 $\mu$ s

1. Min, typ, and max refer to variation due to functional configuration and the raw TVS value. The actual internal correction time will vary based on the raw TVS value.
2. The pulse width varies depending on the time taken to complete the internal calibration multiplication, this can be up to 375 ns.

**Note:** Once the TVS block is active, the enable signal is sampled 25 ns before the falling edge of valid. The next enabled channel in the sequence 0-1-2-3 is started; that is, if channel 0 has just completed and only channels 0 and 3 are enabled, the next channel will be 3. When all the enabled channels in the sequence 0-1-2-3 are completed, the TVS waits for the conversion rate timer to expire. The enable signal may be changed at any time if it changes to 4'b0000 while valid is asserted (and 25 ns before valid is de-asserted), then no further conversions will be started.

**Table 92 • Temperature and Voltage Sensor Electrical Characteristics**

Parameter	Min	Typ	Max	Unit	Condition
Temperature sensing range	-40		125	°C	
Temperature sensing accuracy	-10		10	°C	

**Table 101 • Cold and Warm Boot**

Parameter	Symbol	Min	Typ	Max	Unit	Condition
The time from $T_{FAB\_READY}$ to ready to program through JTAG/SPI-Slave		0	0	0	ms	
The time from $T_{FAB\_READY}$ to auto-update start			$T_{PUF\_OVHD}^1$	$T_{PUF\_OVHD}^1$	ms	
The time from $T_{FAB\_READY}$ to programming recovery start			$T_{PUF\_OVHD}^1$	$T_{PUF\_OVHD}^1$	ms	
The time from $T_{FAB\_READY}$ to the tamper flags being available	$T_{TAMPER\_READY}$	0	0	0	ms	
The time from $T_{FAB\_READY}$ to the Athena Crypto co-processor being available (for S devices only)	$T_{CRYPTO\_READY}$	0	0	0	ms	

1. Programming depends on the PUF to power up. Refer to  $T_{PUF\_OVHD}$  at section [Secure NVM Performance](#) (see page 58).

## 7.9.8 I/O Calibration

The following tables specify the initial I/O calibration time for the fastest and slowest supported VDDI ramp times of 0.2 ms to 50 ms, respectively. This only applies to I/O banks specified by the user to be auto-calibrated.

**Table 102 • I/O Initial Calibration Time (TCALIB)**

Ramp Time	Min (ms)	Max (ms)	Condition
0.2 ms	0.98	2.63	Applies to HSIO and GPIO banks
50 ms	41.62	62.19	Applies to HSIO and GPIO banks

### Notes:

- The user may specify any VDDI ramp time in the range specified above. The nominal initial calibration time is given by the specified VDDI ramp time plus 2 ms.
- In order for IO calibration to start, VDDI and VDDAUX of the I/O bank must be higher than the trip point levels specified in [I/O-Related Supplies](#) (see page 66).

**Table 103 • I/O Fast Recalibration Time (TRECALIB)**

I/O Type	Min (ms)	Typ (ms)	Max (ms)	Condition
GPIO bank	0.16	0.20	0.24	GPIO configured for 3.3 V operation
HSIO bank	0.20	0.25	0.30	HSIO configured for 1.8 V operation

**Note:** In order to obtain fast re-calibration, the user must assert the relevant clock request signal from the FPGA fabric to the I/O bank controller.

The following table describes the time to enter Flash\*Freeze Mode and to exit Flash\*Freeze mode.

**Table 104 • Flash\*Freeze**

Parameter	Symbol	Min	Typ	Max	Unit	Condition
The time from Flash*Freeze entry command to the Flash*Freeze state	T <sub>FF_ENTRY</sub>		59		μs	
The time from Flash*Freeze exit pin assertion to fabric operational state	T <sub>FF_FABRIC_UP</sub>		133		μs	
The time from Flash*Freeze exit pin assertion to I/Os operational	T <sub>FF_IO_ACTIVE</sub>		143		μs	

## 7.10 Dedicated Pins

The following section describes the dedicated pins.

### 7.10.1 JTAG Switching Characteristics

The following table describes characteristics of JTAG switching.

**Table 105 • JTAG Electrical Characteristics**

Symbol	Description	Min	Typ	Max	Unit	Condition
T <sub>DISU</sub>	TDI input setup time	0.0			ns	
T <sub>DIHD</sub>	TDI input hold time	2.0			ns	
T <sub>TMSSU</sub>	TMS input setup time	1.5			ns	
T <sub>TMSHD</sub>	TMS input hold time	1.5			ns	
F <sub>TCK</sub>	TCK frequency		25		MHz	
T <sub>TCKDC</sub>	TCK duty cycle	40	60		%	
T <sub>TDOQO</sub>	TDO clock to Q out		8.4	ns	C <sub>LOAD</sub> = 40 pf	
T <sub>TRSTBCQ</sub>	TRSTB clock to Q out		23.5	ns	C <sub>LOAD</sub> = 40 pf	
T <sub>TRSTBPW</sub>	TRSTB min pulse width	50			ns	
T <sub>TRSTBREM</sub>	TRSTB removal time	0.0			ns	
T <sub>TRSTBREC</sub>	TRSTB recovery time	12.0			ns	
C <sub>IN_TDI</sub>	TDI input pin capacitance		5.3	pf		
C <sub>IN_TMS</sub>	TMS input pin capacitance		5.3	pf		
C <sub>IN_TCK</sub>	TCK input pin capacitance		5.3	pf		
C <sub>IN_TRSTB</sub>	TRSTB input pin capacitance		5.3	pf		

### 7.10.2 SPI Switching Characteristics

The following tables describe characteristics of SPI switching.

**Table 106 • SPI Master Mode (PolarFire Master) During Programming**

Parameter	Symbol	Min	Typ	Max	Unit	Condition
SCK frequency	F <sub>MSCK</sub>			20	MHz	

1. With DPA counter measures.

**Table 115 • HMAC**

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
HMAC-SHA-256 <sup>1</sup> , 256-bit key	512	7477	2361
	64K	88367	2099
HMAC-SHA-384 <sup>1</sup> , 384-bit key	1024	13049	2257
	64K	106103	2153

1. With DPA counter measures.

**Table 116 • CMAC**

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
AES-CMAC-256 <sup>1</sup> (message is only authenticated)	128	446	9058
	64K	45494	111053

1. With DPA counter measures.

**Table 117 • KEY TREE**

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
128-bit nonce + 8-bit optype		102457	2751
256-bit nonce + 8-bit optype		103218	2089

**Table 118 • SHA**

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
SHA-1 <sup>1</sup>	512	2386	1579
	64K	77576	990
SHA-256 <sup>1</sup>	512	2516	884
	64K	84752	938
SHA-384 <sup>1</sup>	1024	4154	884
	64K	100222	938
SHA-512 <sup>1</sup>	1024	4154	881
	64K	100222	935

1. With DPA counter measures.

**Table 119 • ECC**

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
ECDSA SigGen, P-384/SHA-384 <sup>1</sup>	1024	12528912	6944
	8K	12540448	5643
ECDSA SigGen, P-384/SHA-384	1024	5502928	6155

ECDSA SigVer, P-384/SHA-384	1024 8K	6421841 6273510	5759 5759
Key Agreement (KAS), P-384		5039125	6514
Point Multiply, P-256 <sup>1</sup>		5176923	4482
Point Multiply, P-384 <sup>1</sup>		12043199	5319
Point Multiply, P-521 <sup>1</sup>		26887187	6698
Point Addition, P-384		3018067	5779
KeyGen (PKG), P-384		12055368	6908
Point Verification, P-384		5091	3049

1. With DPA counter measures.

**Table 120 • IFC (RSA)**

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
Encrypt, RSA-2048, e=65537	2048	436972	8,972
Encrypt, RSA-3072, e=65537	3072	962162	12,583
Decrypt, RSA-2048 <sup>1</sup> , CRT	2048	26862392	15900
Decrypt, RSA-3072 <sup>1</sup> , CRT	3072	75153782	22015
Decrypt, RSA-4096, CRT	4096	89235615	23710
Decrypt, RSA-3072, CRT	3072	37880180	18638
SigGen, RSA-3072/SHA-384 <sup>1</sup> ,CRT, PKCS #1 V 1.5	1024 8K	75197644 75213653	20032 19303
SigGen, RSA-3072/SHA-384, PKCS #1, V 1.5	1024 8K	148090970 148102576	14642 13936
SigVer, RSA-3072/SHA-384, e = 65537, PKCS #1 V 1.5	1024 8K	970991 982011	12000 11769
SigVer, RSA-2048/SHA-256, e = 65537, PKCS #1 V 1.5	1024 8K	443493 453007	8436 8436
SigGen, RSA-3072/SHA-384, ANSI X9.31	1024 8K	147138254 147155896	13945 13523
SigVer, RSA-3072/SHA-384, e = 65537, ANSI X9.31	1024 8K	973269 983255	11313 11146

1. With DPA counter measures.

**Table 121 • FFC (DH)**

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
SigGen, DSA-3072/SHA-384 <sup>1</sup>	1024 8K	27932907 27942415	13969 13501
SigGen, DSA-3072/SHA-384	1024	12086356	13602
SigVer, DSA-3072/SHA-384	1024 8K	24597916 24229420	15662 15133

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